State Program on Nanotechnologies and Nanomaterials: Integrating Research, Innovation and Education

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- **1. Reforms in science in the Republic of Moldova**
- 2. Innovative system
- 3. Scientific educational cluster UnivER SCIENCE
- 4. Nanoscience and nanotechnologies: main players
- 5. State program on nanotechnologies and nanomaterials
- 6. Some important projects
- 7. Conclusions

Reforms in Science

The Code on Science and Innovation

Ratified by the Parliament on July 15, 2004

The Code is a unique legislative document, which regulates relationships in the sphere of science and innovation

<u>According to the Code</u>

• The Academy of Sciences becomes the unique public institution of national importance in the field of science and innovation.

• The Academy of Sciences is authorized with the Government's competence in the field of scientific research.

The Academy of Sciences of Moldova, as a public institution, in compliance with the Code, had concluded a Partnership Agreement with the Government of the Republic of Moldova

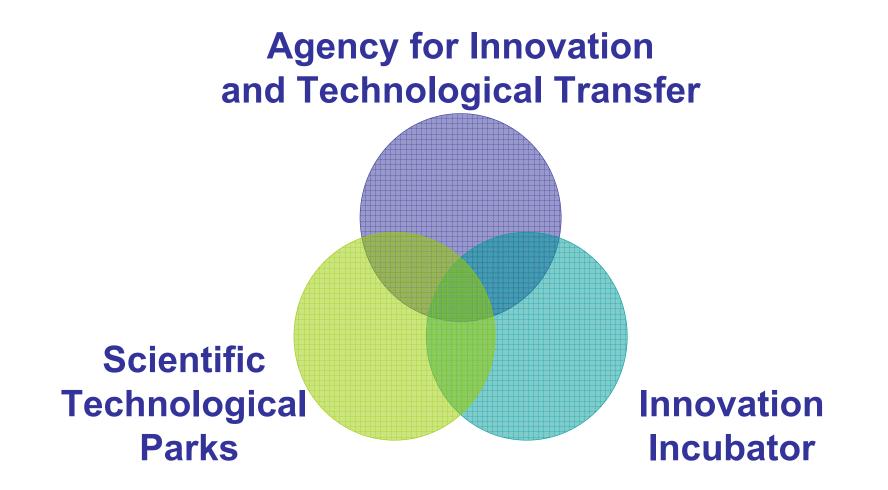
Partnership Agreement Stipulates:

- The level of financial support of Science and Innovation fields;
- Strategic Priorities concerning the Development of Science and Innovation fields;
- The reorganization of science and innovation fields.

National Programs in Science and Innovation

- State Programs (10 State Programs)
- Program for Young Scientists
- Program for Equipment
 Purchasing
- Program for Technology
 Transfer Projects

Innovative system of the Academy



LAW ON TECHNOLOGY PARKS AND INNOVATIVE INCUBATORS No. 138-XVI of 21.06.2007

Important peculiarities 1. Geographical freedom.

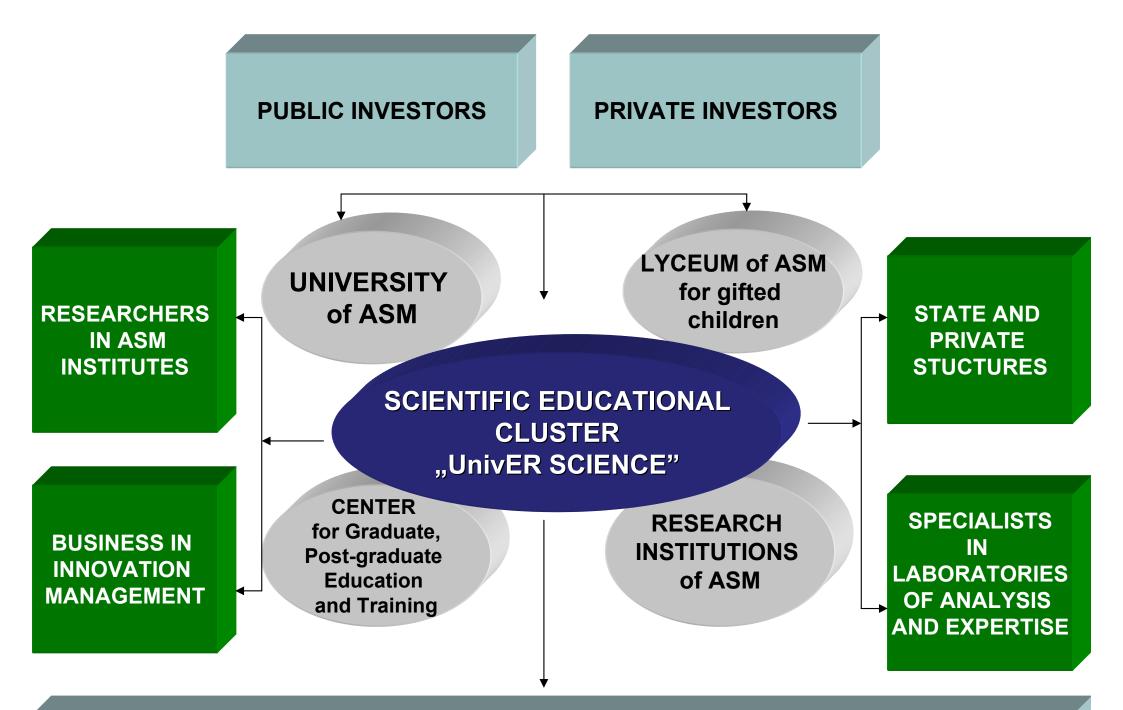
- 2. Fiscal and customs facilities:
 - Exemption from payment of VAT (20%) on goods and services imported from abroad;
 - Exemption from payment of VAT (20%) on goods and services bought on the territory of the Republic of Moldova;
 - Exemption from payment of customs taxes (5%) on imported goods and services.

Scientific educational Cluster of the Academy of Sciences of Noldova

"UNIVER SCIENCE"



Education through RESEARCH



RESEARCH AND EDUCATION MEDIUM FAVORABLE FOR KEEPING ON THE SUPPLY OF PERSONNEL FOR RESEARCH AND TECHNOLOGICAL TRANSFER STRUCTURES

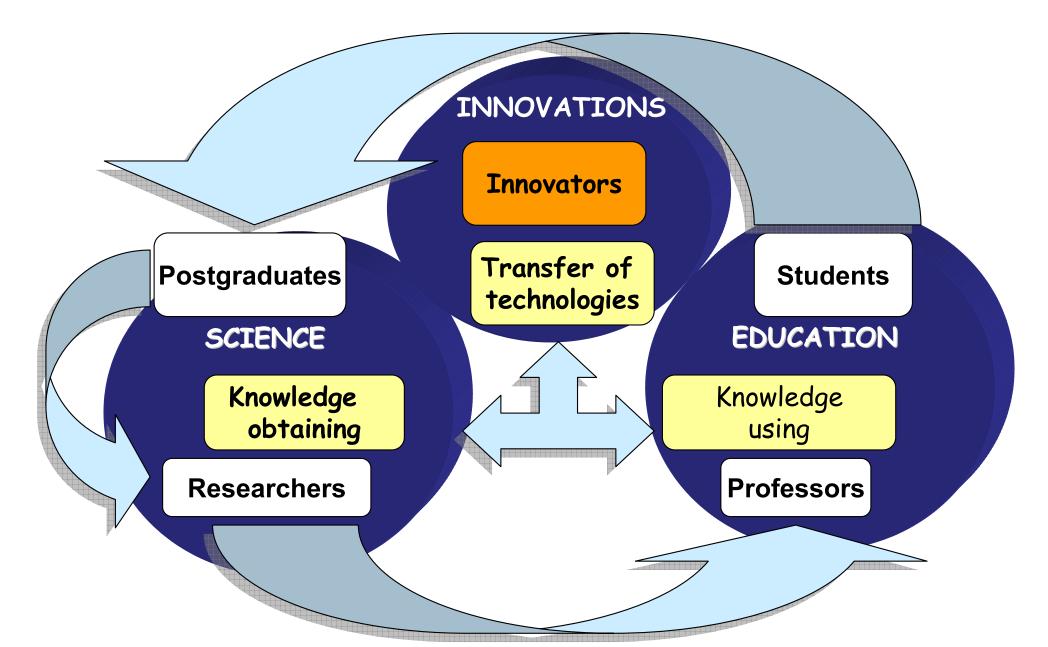
Nucleus of the Cluster

- Lyceum of ASM for talented children;
- University of ASM;
- Research institutions;
- Scientific technological parks;
- Innovative incubator.

SPECIFIC OBJECTIVES OF THE SCIENTIFIC EDUCATION CLUSTER

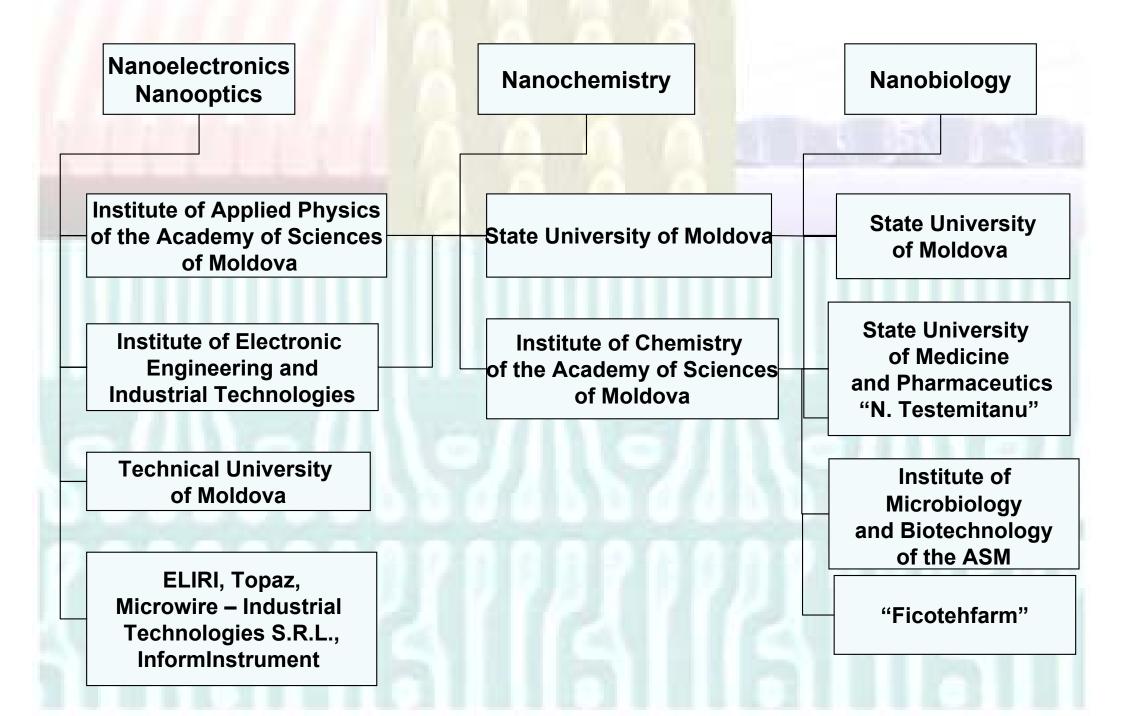
- Professional education of researchers;
- High performance;
- Competitiveness based on scientific criteria, insuring specialization on domains and excellence at the intersection of various fields;
- Growth of innovative capacity through program expansion;
- Management experience;
- Obtaining of management and marketing capacity in research-development.

Integration of science, Innovation and education

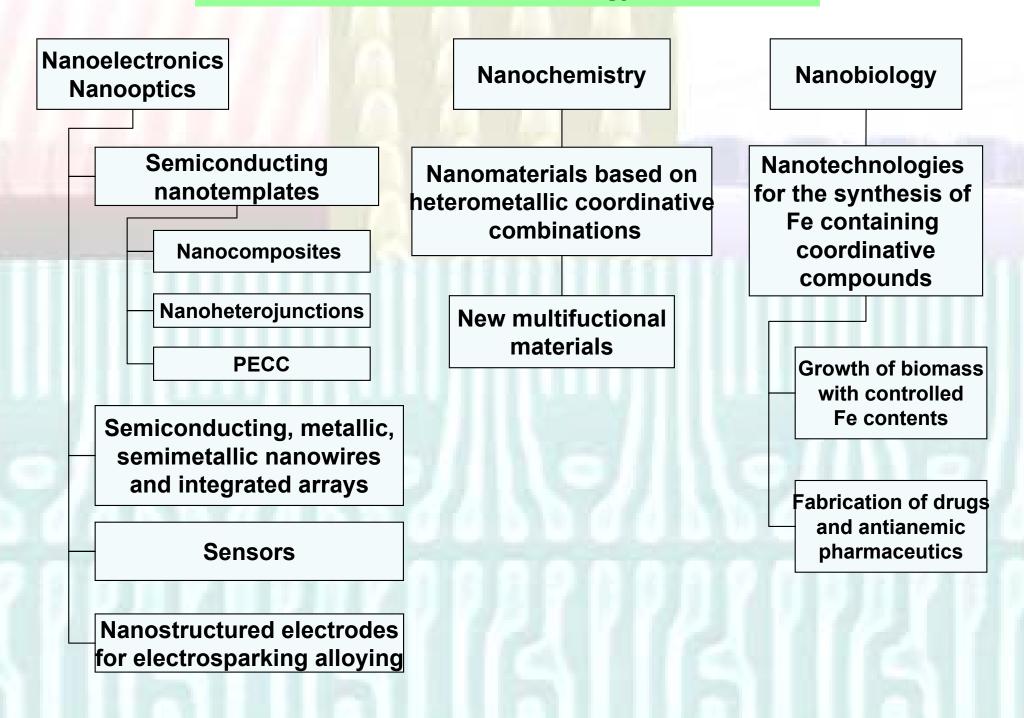


Nanoscience and Nanotechnologies in Moldova: Main players

Nanoscience and nanotechnology in Moldova



Nanoscience and nanotechnology in Moldova

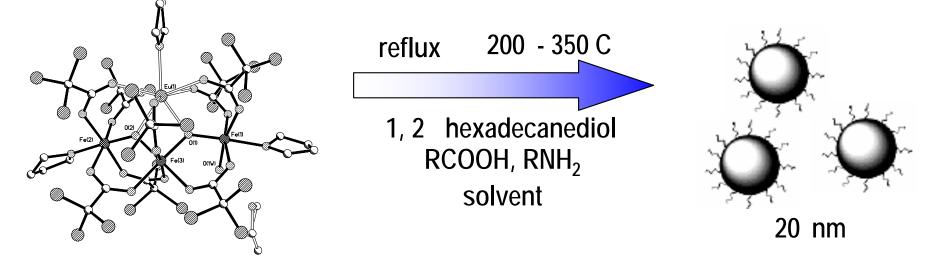


Activities in the field of nanotechnologies in the Republic of Moldova



Nanotechnologies in the Republic of Moldova

1. Chemical and electrochemical technologies for growth of clusters, nanocrystals, quantum dots etc.

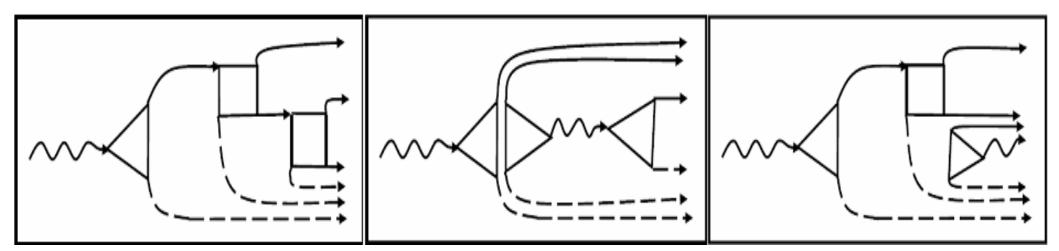


2. Technologies for layer deposition, including epitaxy Gan zno Gaas in powers

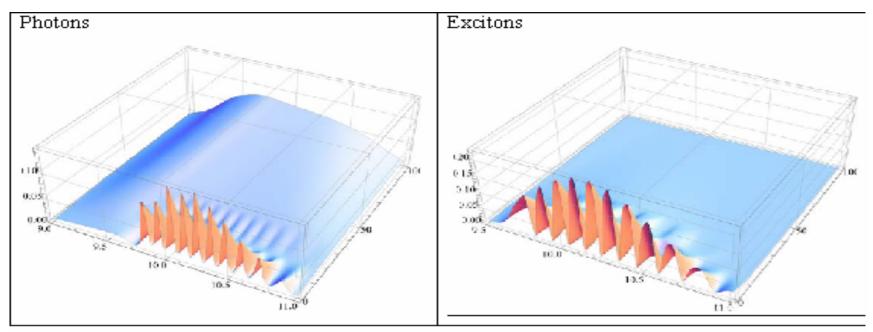
3. Methods for the fabrication of nanowires, nanostructures and integrated networks on their basis

Theoretical support

Multiplication of charged carriers in semiconductor quantum dots

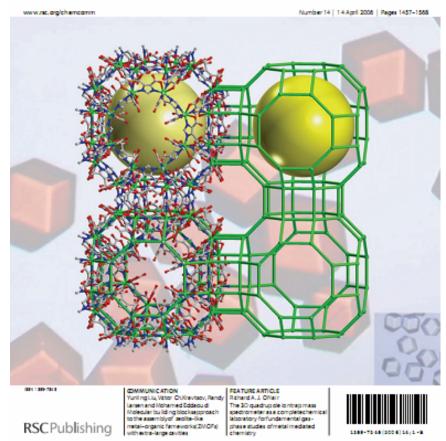


Transmission and reflection of ultrashort laser pulses From thin semiconductor films



ChemComm

Chemical Communications



Molecular building blocks approach to the assembly of zeolite-like metal–organic frameworks with large cavities



rapid research letters

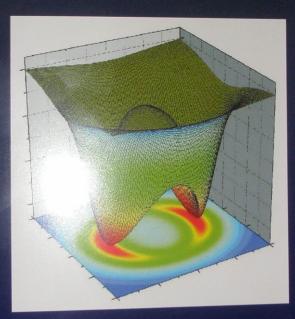


Prediction of negative index material lenses based on metallo-dielectric nanotubes (V. V. Sergentu, I. M. Tiginyanu, V. V. Ursaki, M. Enachi, S. P. Albu, and P. Schmuki, p. 242)

2 • 5 • October 2008

April 2009

Journal of *Number 1 www.aspbs.com/jno* **NANOELECTRONICS** and **OPTOELECTRONICS**



A Special issue on **Electron and Phonon Properties of Nanostructures** *Guest Editor: Evghenii P. Pokatilov* Editor-in-Chief: Alexander A. Balandin, USA



Guest Editor E.P. Pokatilov Republic of Moldova

New State Program on Nanotechnologies and Nanomaterials in Moldova

State Program on Nanotechnologies and Nanomaterials

<u>Cluster 1.</u> Novel nanocomposite, nanoporous and ordered nanostructured materials for optoelectronic and photonic applications

- 1. Development of 2D and 3D metallo-dielectric and metallo-semiconductor structures for electronic and photonic applications (Ion Tiginyanu).
- 2. Elaboration of nanocomposites based on organic-inorganic materials for luminescent and diffraction devices (Andrei Andriesh).
- 3. New metalorganic nanoporous absorbent materials (Bourosh Paulina).
- 4. Synthesis and characterization of thermal properties of new polymeric nanocomposite materials with high thermal stability (Ion Dranca).

<u>Cluster 2.</u> Novel materials for energy conversion and storage

- 1. Elaboration of nanostructured composites of lead and bismuth chalcogenides for energy conversion systems (Andrei Nicorici).
- 2. Semiconductor colloidal nanocrystals for applications in infra-red photoelectrical devices (Leonid Culiuc).
- **3.** New nanometric multi-layer semiconductor structures for applications in technologies of energy conversion and storage (Igor Evtodiev).

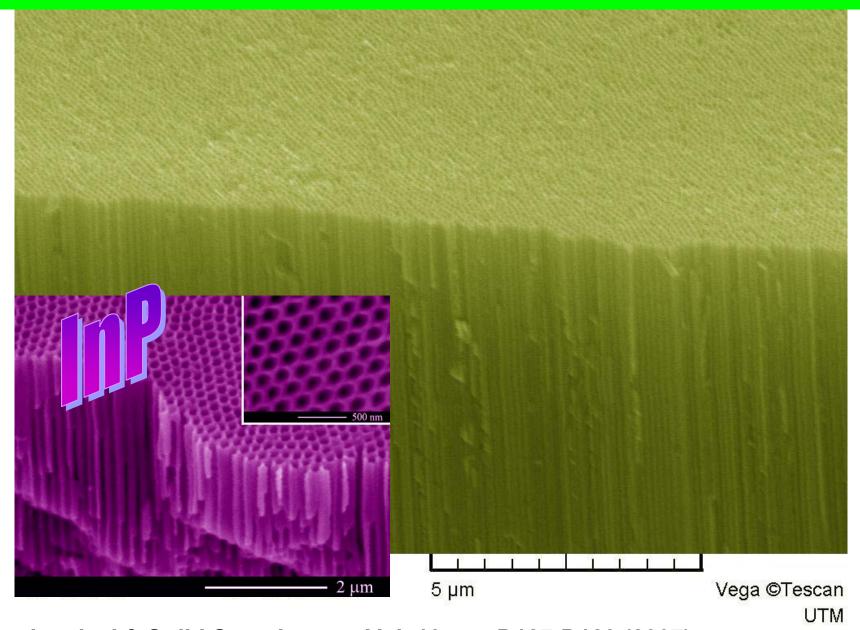
State Program on Nanotechnologies and Nanomaterials

<u>Cluster 3.</u> Technologies of thin films and multi-layer structures for applications in machine building and electronics

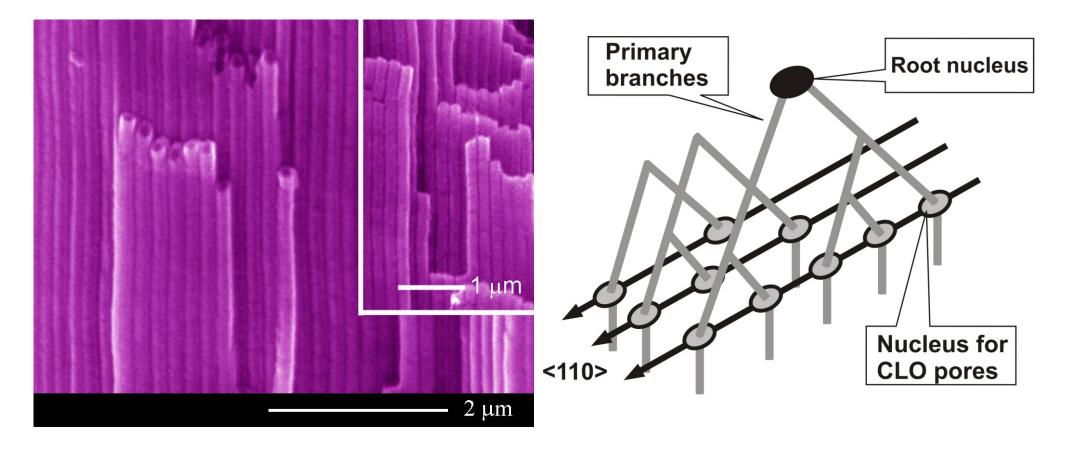
- 1. Electrosparking technology of discrete chemo-thermal treatment of surfaces for anticorrosive protection of machine parts (Alexandru Balanici).
- 2. Electrodeposition of multi-layer nanocomposites and study of corrosive, tribological and magnetic properties for applications (Alexandru Dicusar).
- **3.** Cost-effective technologies for growth of nanostructured ZnO films for photonic and nanoelectronic applications (Emil Rusu).
- 4. Elaboration of GaInP/GaAs(InP) nanostructured films by Vapor Phase Epitaxy for electronic applications (Leonid Gorceac).

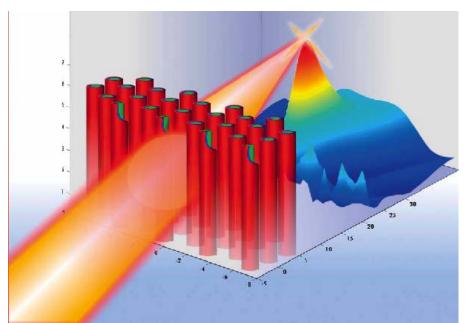
Achievements in the field of nanotechnologies in the Republic of Moldova

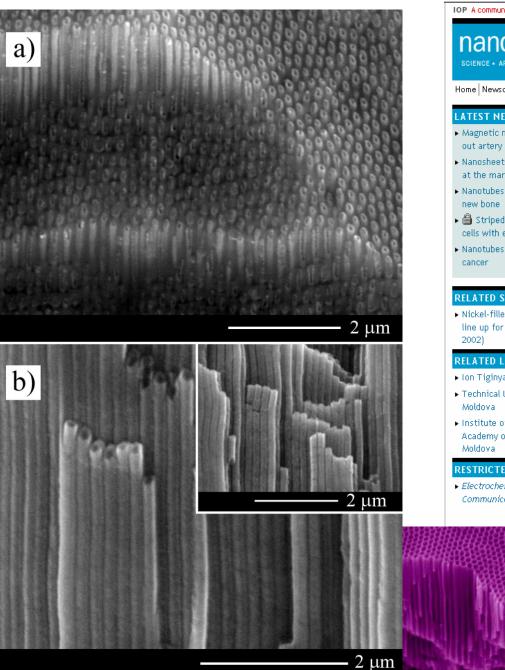
Nanotemplates for nanofabrication

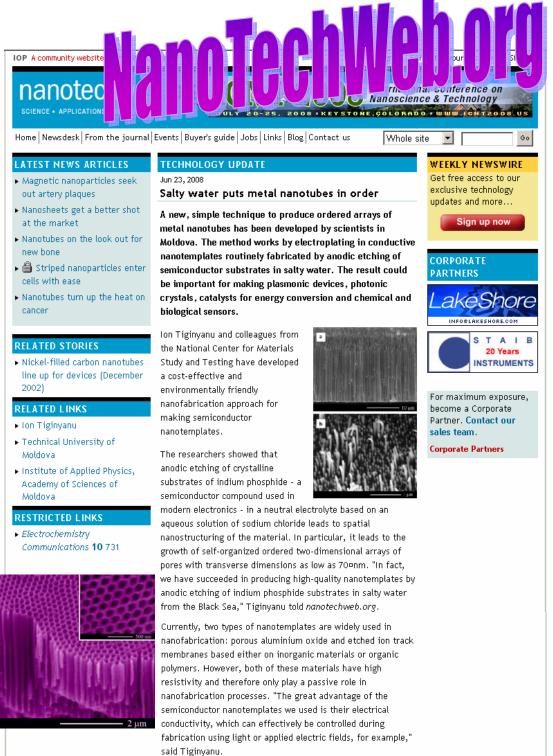


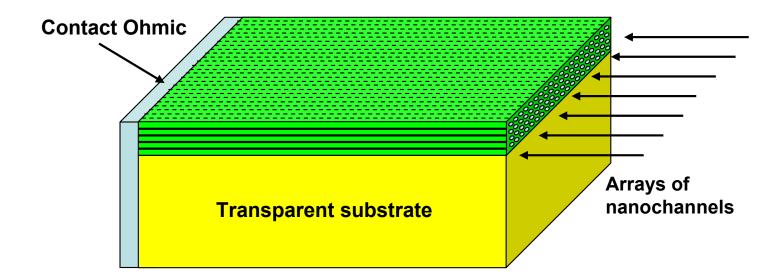
Electrochemical & *Solid-State Letters*, Vol. 10, pp. D127-D129 (2007); *Physica Status Solidi (RRL) – Rapid Research Letters*, Vol. 1, issue 3, pp. 98-100 (2007)

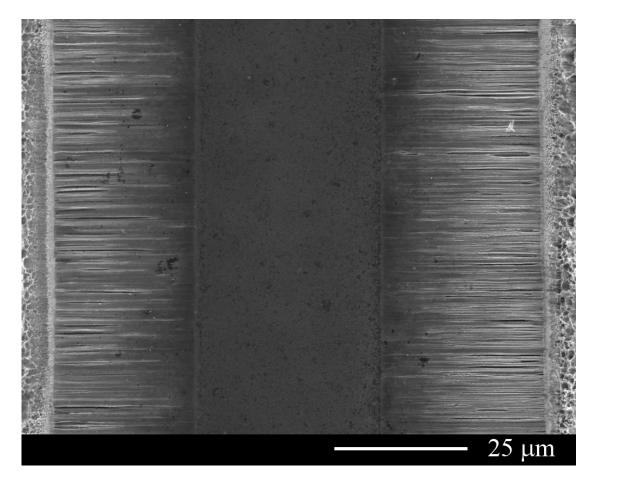






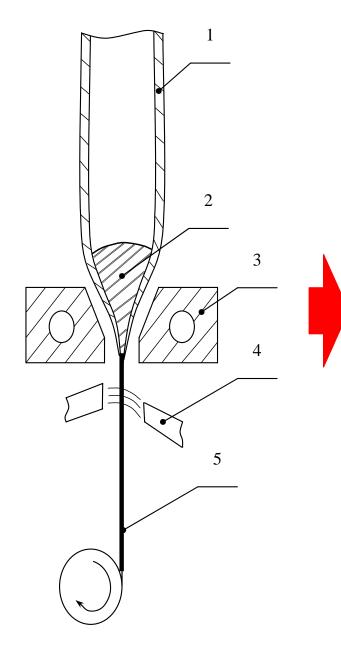


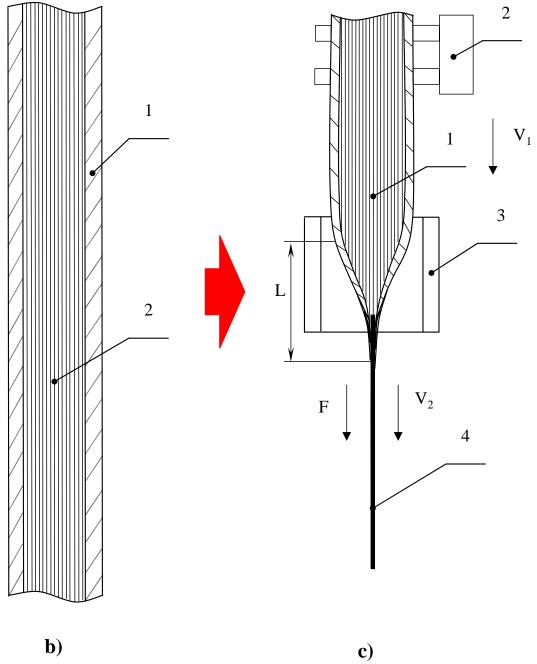




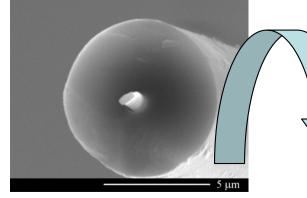


Arrays of nanowires in glass envelopes

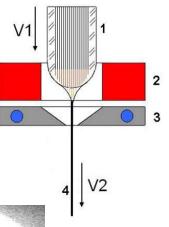


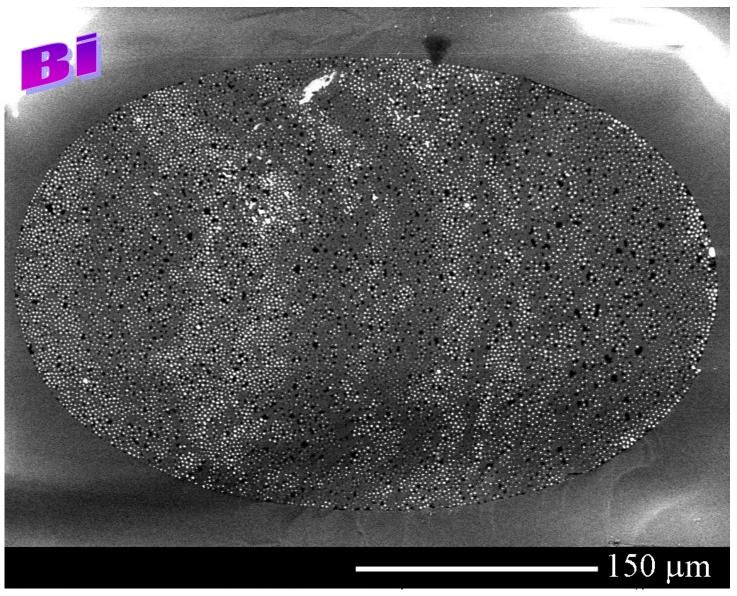


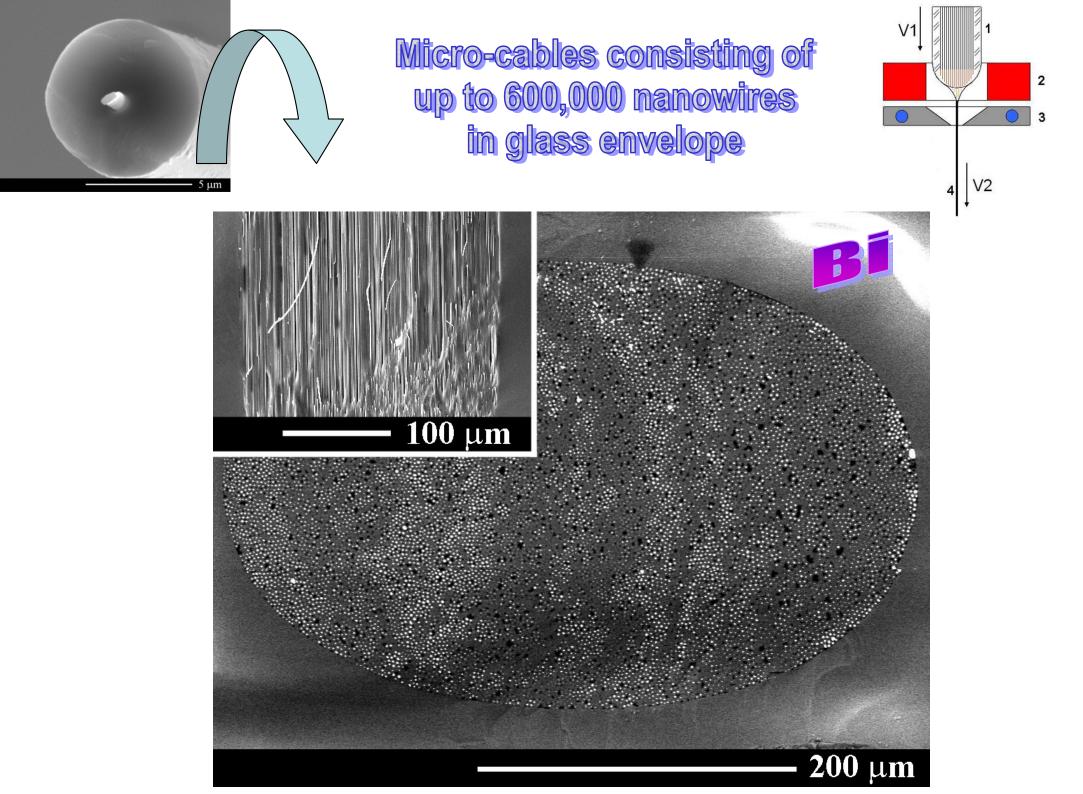
a)

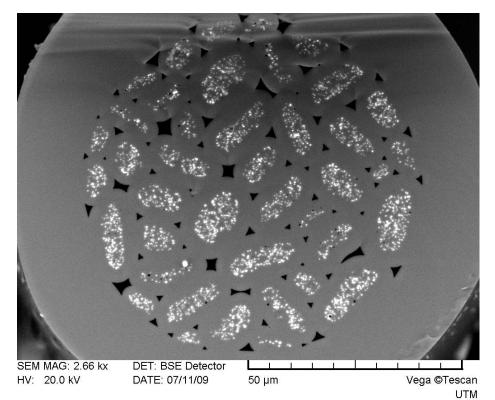


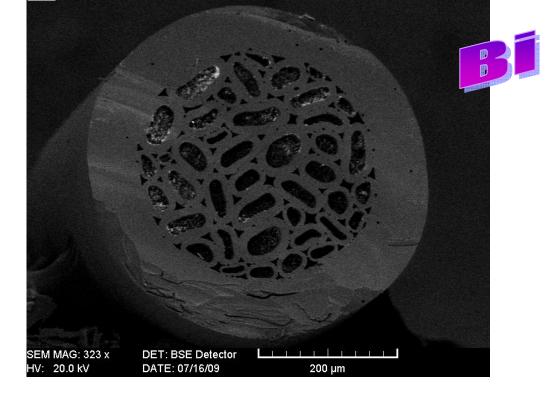
Micro-cables consisting of up to 600,000 nanowires in glass envelope

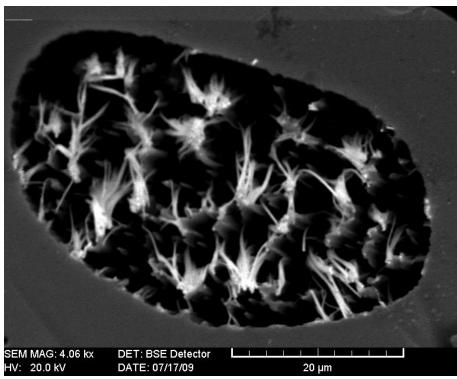


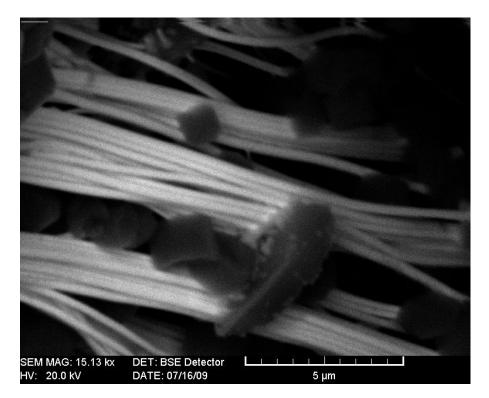


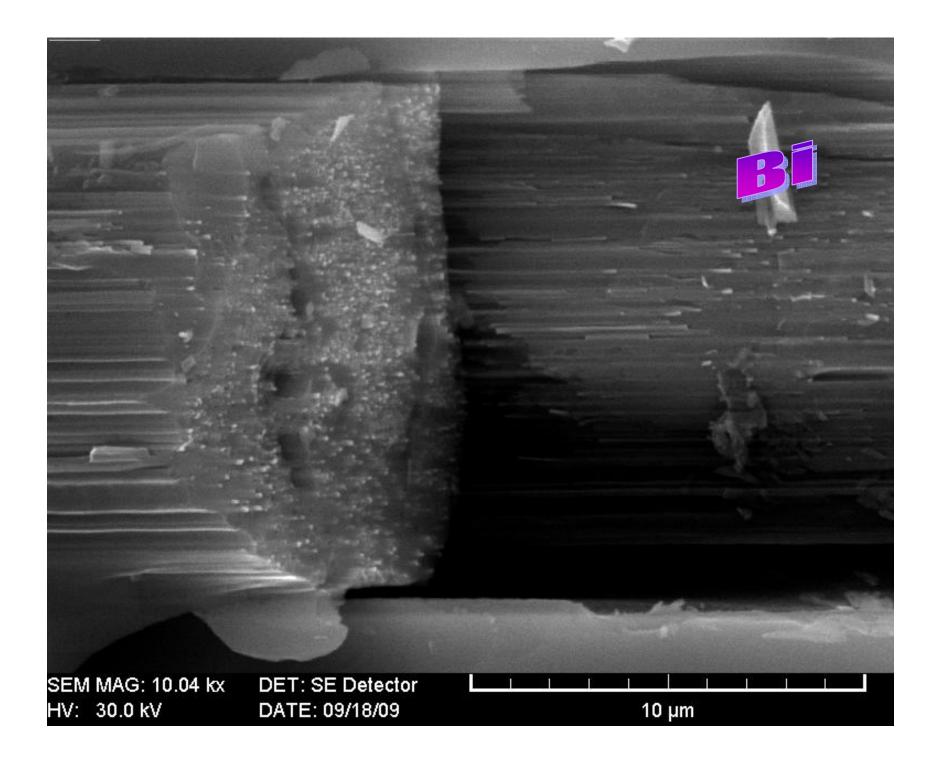


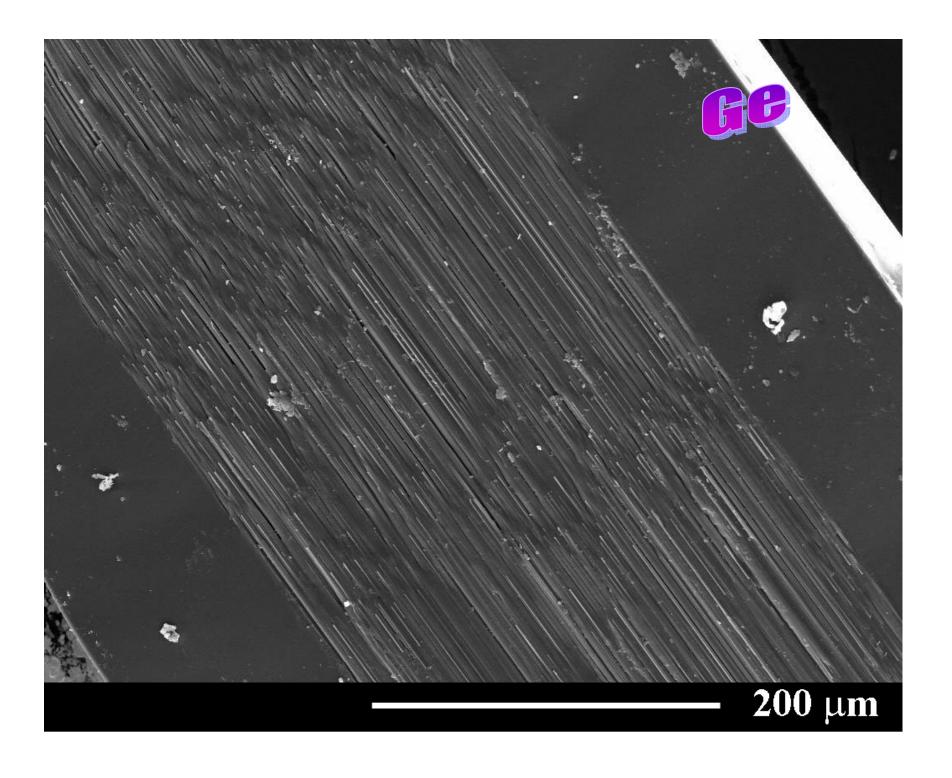


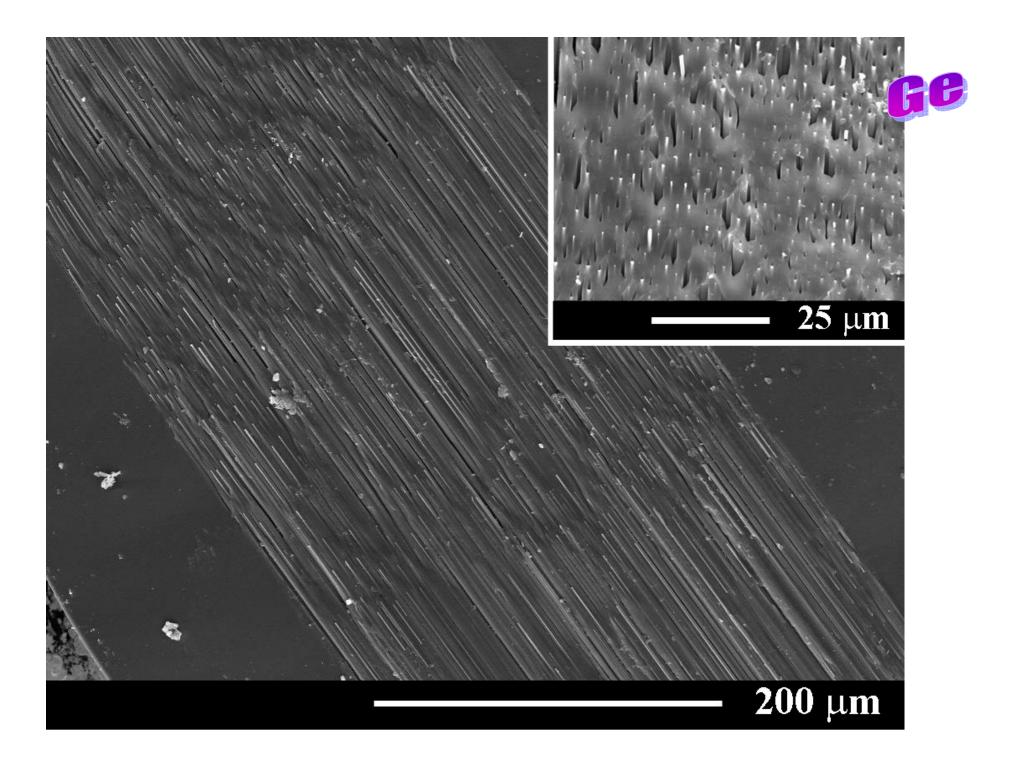


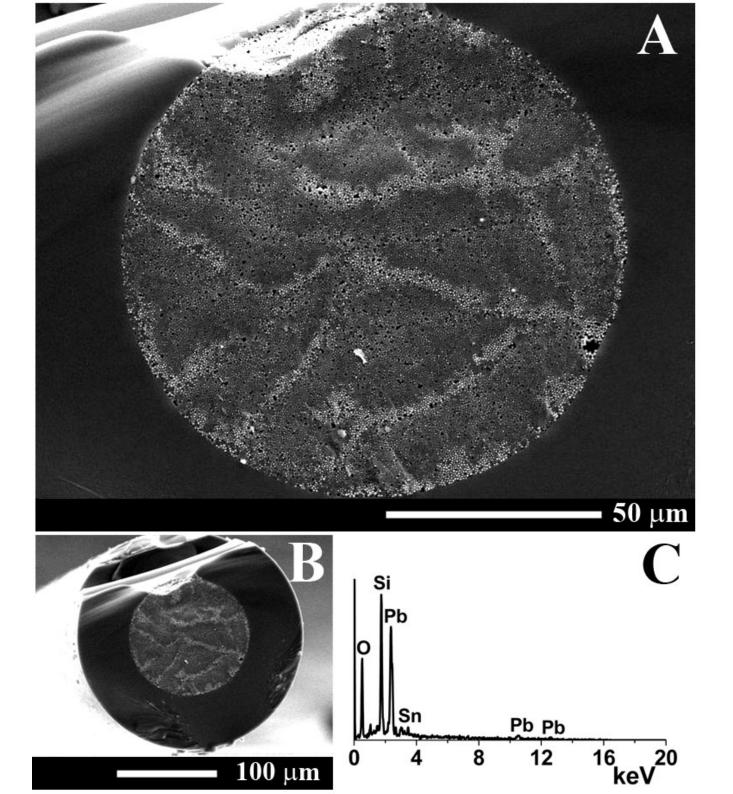






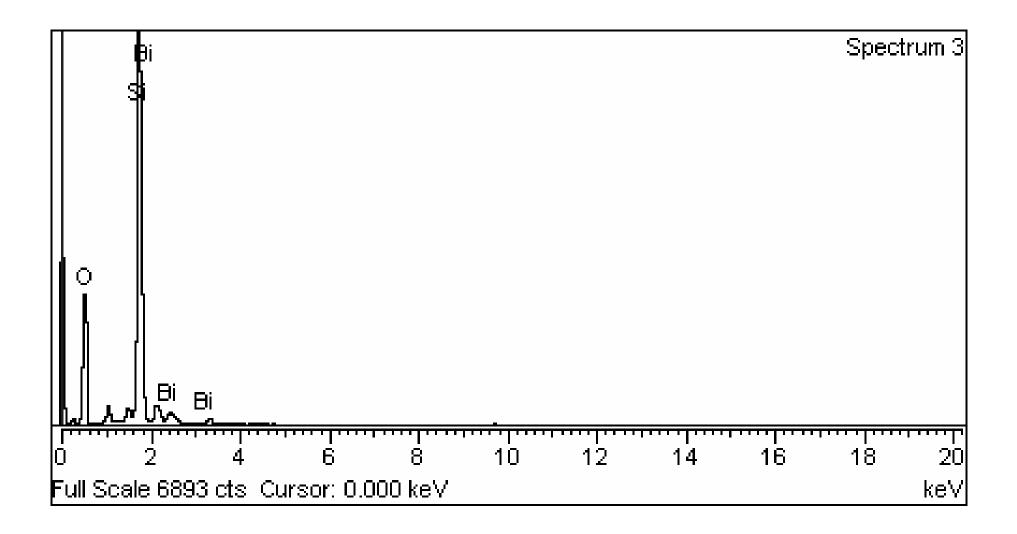


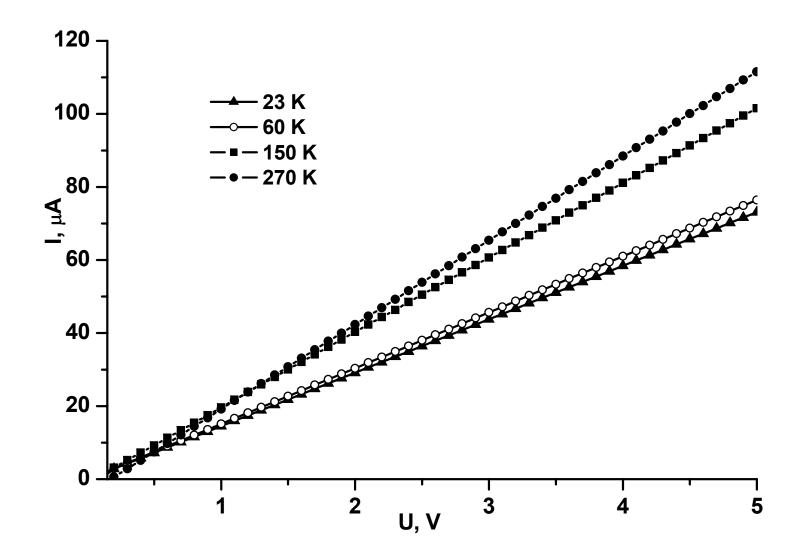






EDX analysis of chemical composition



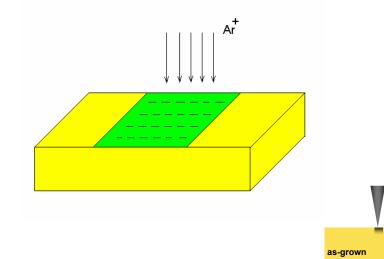


Volt-ampere characteristics at different temperatures of Ga/In electrical contacts to arrays of Bi nanowires in glass envelope.

National Center for Materials Study and Testing



1. Direct "writing" of the negative charge by focused ion beam (FIB)



lon beam treatment

• 2-keV-Ar ions at the dose 3 x 10¹² cm⁻²

 30-keV Ga ions at the dose 6.6 x 10¹² cm⁻², beam current of 150 pA (penetration 14 nm), pixel format (1 pixel 30 nm)

2. Photoelectrochemical etching of the FIB-treated structures

Ga-ion beam Spot size: 8 - 500 nm

Implanted

30kV. 1013 cm-2

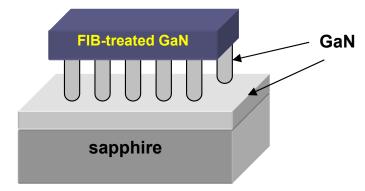
PEC etching was carried out in stirred 0.1 mol aqueous solution of KOH under in-situ ultraviolet (UV) illumination provided by focusing the radiation of a 350 W Hg lamp to a spot of about 5 mm in diameter on the GaN surface exposed to electrolyte.

In most cases we used MOCVD-grown n-GaN layers with electron concentration of 1.7 x 10¹⁷ cm⁻³, the density of dislocations was in the range of 10⁹-10¹⁰ cm⁻².

Surface Charge Lithography

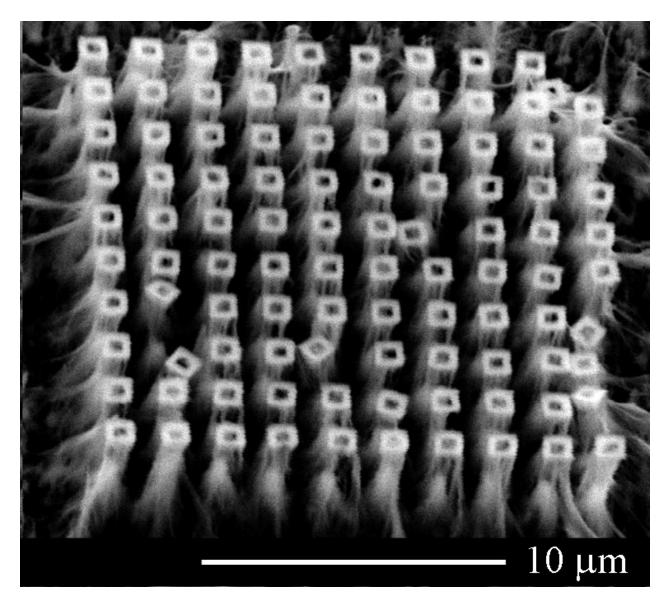


Network of submicrometer structures for photonic applications



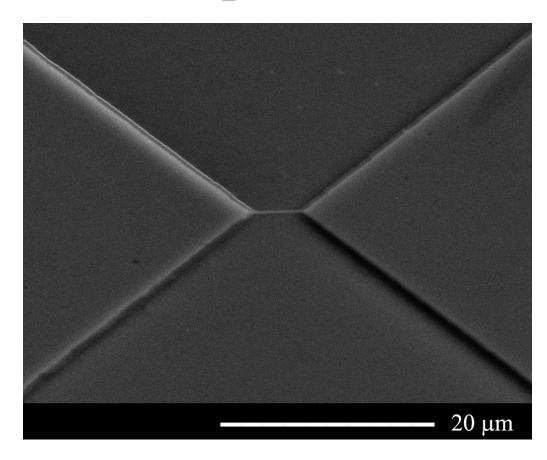
Hollow square membranes of Gan supported Galy by whiskers

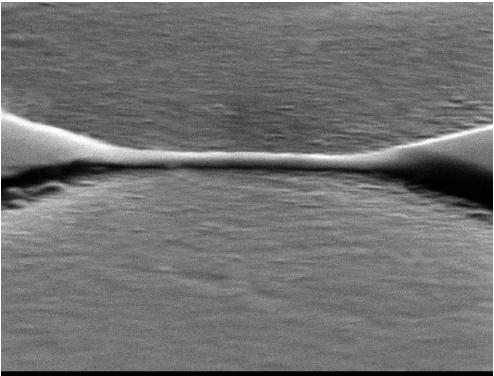
Proc. SPIE, Vol. 7216, 72160Y (2009).



GaN nanowire prepared using SCL

top view





magnified lateral view

2 µm



Growth of semiconductor dots

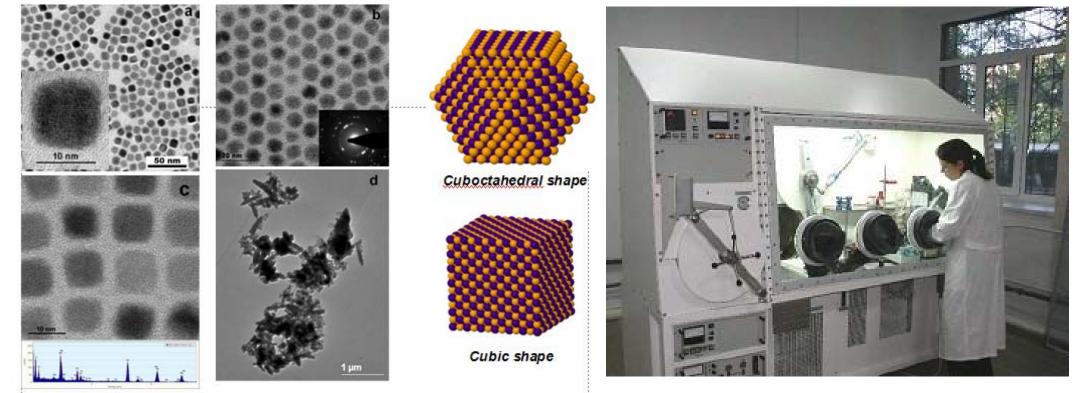


for a new generation of solar cells

Au fost elaborate tehnologii de sinteză a nanocristalelor calcogenidelor de plumb, caracterizate prin reproductibilitate și randament înalt de obținere a punctelor cuantice PbSe/PbS și PbTe cu mono-dispersie dimensională omogenă.

temperatura	dimensiunile
•200 °C	10 nm
•180 °C	7.2 nm
•160 °C	6,6 nm
•140 °C	< 3 nm

Datele XRD corelează cu datele TEM



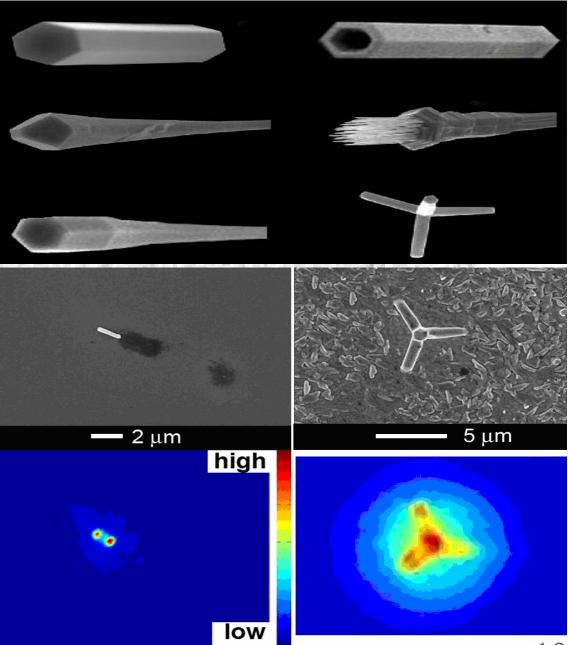


Micro-lasers based on ZnO



Au fost obtinute noi structuri de micro și nanolasere în baza de ZnO. Avantajul structurilor studiate țin de reducerea dimensiunilor rezonatorului laser, micşorarea pragului de emisie stimulată, extinderea diversitătii nanorezonatoarelor pentru utilizare în circuite optoelectronice şi fotonice.

Applied Physics Letters Vol. 95, 171101 (2009)



Nanotechnology Platform



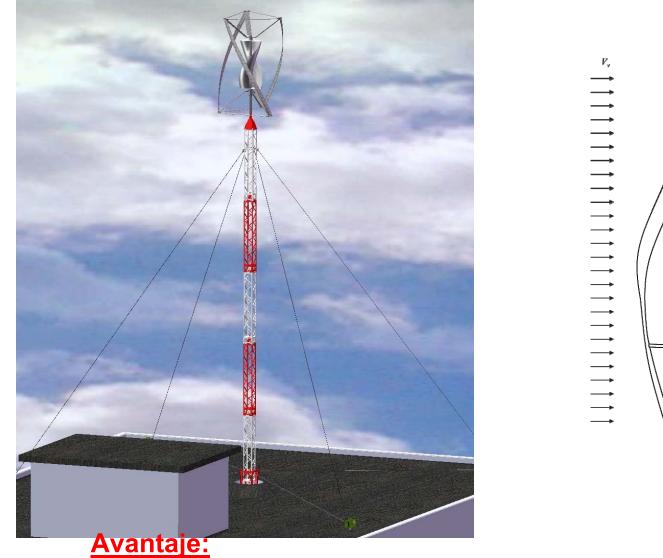
Micro-hydro power station



(diametrul rotorului *D* = 4*m*, înălțimea submersată a palei *h* = 1,4*m*, lungimea cordului palei *I* =1,3 *m*) (MHCF D4x1,5 ME)

Technical University of Moldova

New types of wind power stations



-majorarea coeficientului de utilizare a energiei eoliene;

- uniformitatea rotirii organului de lucru;
- -zgomot și vibrații reduse.

Technical University of Moldova

Conclusions

- Development of cost-effective technologies and promising nanomaterials;
- Progress in developing semiconductor nanotemplates for nanofabrication;
- Pronounced tendencies in diminishing the diameter of glass-coated metal microwires and fabrication of ordered arrays of metal nanowires;
- Elaboration of metal-semiconductor and polymer-semiconductor nanocomposites for optoelectronic applications;
- Development of new laser materials and rare-earth-doped fiber amplifiers;
- Growth and characterization of magnetic materials;
- Building of new coordination and supramolecular polyfunctional compounds;
- Photothermoplastic recording as a tool of color imaging using vitreus chalcogenide semiconductors as photosensitive layers;
- Elaboration and characterization of novel device structures.

Thank you

for your kind attention!